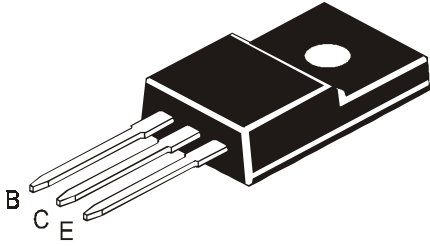


**PNP SILICON PLANAR DARLINGTON POWER TRANSISTOR**

**CJF6668**



**TO-220FP Fully Isolated  
Plastic Package**

**Complementary CJF6388**

**General Purpose Darlington Amplifier and Switching Applications**

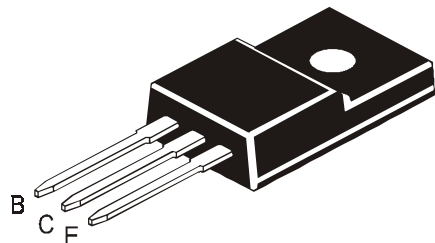
**ABSOLUTE MAXIMUM RATINGS.**

DESCRIPTION	SYMBOL	VALUE	UNIT
Collector Base Voltage	$V_{CBO}$	100	V
Collector Emitter Voltage	$V_{CEO}$	100	V
Emitter Base Voltage	$V_{EBO}$	5	V
RMS Isolation Voltage ( for 1sec,R.H. <30%, $T_A=25^\circ\text{C}$ )	(1) $V_{ISOL}$ (a)	3500	$V_{RMS}$
	(b)	1500	$V_{RMS}$
Collector Current - Continuous	$I_C$	10	A
		Peak (2)	15
Base Current	$I_B$	1	A
Total Power Dissipation @ $T_c=25^\circ\text{C}$	$P_{D^{**}}$	40	W
Derate Above $25^\circ\text{C}$		0.31	W/ $^\circ\text{C}$
Total Power Dissipation @ $T_a=25^\circ\text{C}$	$P_D$	2	W
Derate Above $25^\circ\text{C}$		0.016	W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	$T_j, T_{stg}$	- 65 to +150	$^\circ\text{C}$
<b>THERMAL RESISTANCE</b>			
From Junction to Case	$R_{th(j-c)**}$	3.2	$^\circ\text{C/W}$
From Junction to Ambient	$R_{th(j-a)}$	62.5	$^\circ\text{C/W}$
Lead Temperature for Soldering Purpose	$T_L$	260	$^\circ\text{C}$

**\*\*Measurement made with thermocouple contacting the bottom insulated mounting surface (in a location beneath the die), the device mounted on a heatsink with thermal grease and a mounting torque of  $\geq 6$  in.lbs.**

**(1) RMS Isolation Voltage : (a) 3500  $V_{RMS}$  with Package in Clip Mounting Position (b) 1500  $V_{RMS}$  with Package in Screw Mounting Position (for 1sec, R.H.<30% , $T_a=25^\circ\text{C}$ ; Pulse Test: Pulse Width  $\leq 300\mu\text{s}$ , Duty Cycle $\leq 2\%$ )**

**(2) Pulse Test : Pulse Width =5ms, Duty Cycle $\leq 10\%$**



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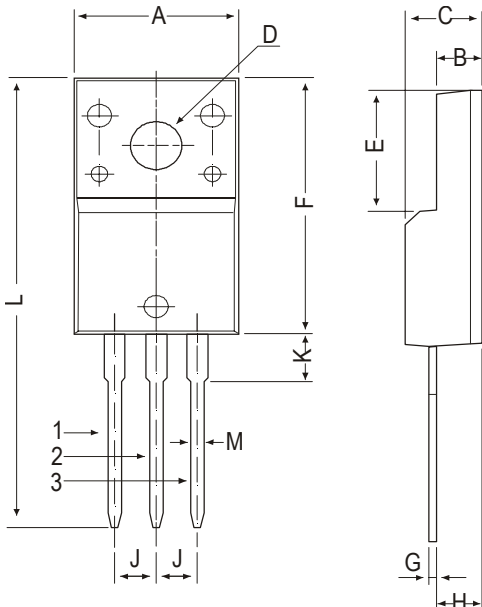
ELECTRICAL CHARACTERISTICS (T<sub>c</sub>=25°C unless specified otherwise)

DESCRIPTION	SYMBOL	TEST CONDITION	MIN	MAX	UNIT
Collector Emitter sustaining Voltage	V <sub>CEO(sus)</sub> *	I <sub>C</sub> =30mA, I <sub>B</sub> =0	100		V
Collector Cut off Current	I <sub>CEO</sub>	V <sub>CE</sub> =80V, I <sub>B</sub> =0		10	μA
	I <sub>CEX</sub>	V <sub>CE</sub> =100V, V <sub>EB(off)</sub> =1.5V		10	μA
		T <sub>C</sub> =125°C			
		V <sub>CE</sub> =100V, V <sub>EB(off)</sub> =1.5V		3	mA
Emitter Cut off Current	I <sub>CBO</sub>	V <sub>CB</sub> =100V, I <sub>E</sub> =0		10	μA
	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0		2	mA
DC Current Gain	h <sub>FE</sub> *	I <sub>C</sub> =3A, V <sub>CE</sub> =4V	3000	15000	
		I <sub>C</sub> =5A, V <sub>CE</sub> =3V	1000		
		I <sub>C</sub> =8A, V <sub>CE</sub> =4V	200		
		I <sub>C</sub> =10A, V <sub>CE</sub> =3V	100		
Collector Emitter Saturation Voltage	V <sub>CE(Sat)</sub> *	I <sub>C</sub> =3A, I <sub>B</sub> =6mA		2	V
		I <sub>C</sub> =5A, I <sub>B</sub> =0.01A		2	V
		I <sub>C</sub> =8A, I <sub>B</sub> =80mA		2.5	V
		I <sub>C</sub> =10A, I <sub>B</sub> =0.1A		3	V
Base Emitter Saturation Voltage	V <sub>BE(Sat)</sub> *	I <sub>C</sub> =5A, I <sub>B</sub> =0.01A		2.8	V
		I <sub>C</sub> =10A, I <sub>B</sub> =0.1A		4.5	V
Base Emitter on Voltage	V <sub>BE(on)</sub> *	I <sub>C</sub> =8A, V <sub>CE</sub> =4V		2.5	V
<b><u>DYNAMIC CHARACTERISTICS</u></b>					
Small Signal Current Gain	h <sub>fe</sub> l	I <sub>C</sub> =1A, V <sub>CE</sub> =5V, f=1MHz	20		
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz		300	pF
Small Signal Current Gain	h <sub>fe</sub>	I <sub>C</sub> =1A, V <sub>CE</sub> =5V, f=1kHz	1000		

\* Pulse Test: Pulse Width ≤300μs, Duty Cycle ≤2 %

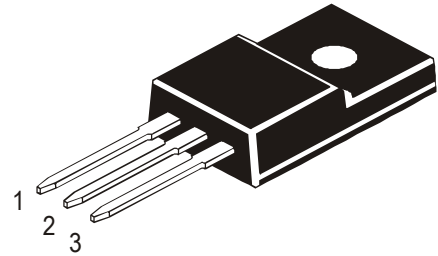
**TO-220FP Fully Isolated Plastic Package**

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DIM	MIN	MAX
A	9.96	10.36
B	2.60	3.00
C	4.50	4.90
D	3.10	3.30
E	7.90	8.20
F	16.87	17.27
G	0.45	0.50
H	2.56	2.96
J	2.34	2.74
K	—	3.08
L	—	30.05
M	—	0.80

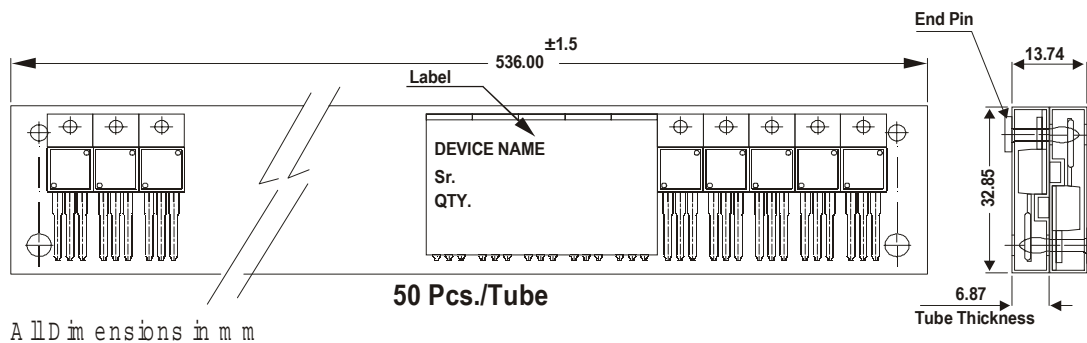
All dimensions in mm.



**Pin Configuration**

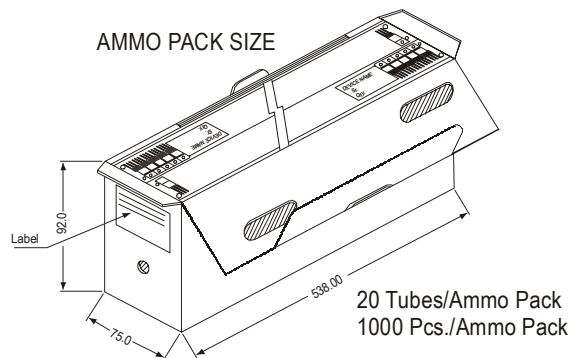
1. Base
2. Collector
3. Emitter

**TO-220 FP Tube Packing**



All dimensions in mm

**AMMO PACK SIZE**



**Packing Detail**

PACKAGE	STANDARD PACK		INNER CARTON BOX		OUTER CARTON BOX		
	Details	Net Weight/Qty	Size	Qty	Size	Qty	Gr Wt
TO-220FP	200 pcs/polybag	396 gm/200 pcs	3" x 7.5" x 7.5"	1K	17" x 15" x 13.5"	16K	36 kgs
	50 pcs/tube	135 gm/50 pcs	3.5" x 3.7" x 21.5"	1K	19" x 19" x 19"	10K	28 kgs

**TO-220FP Fully Isolated  
Plastic Package****Disclaimer**

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